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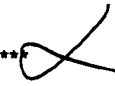
Bib Data Sheet

SERIAL NUMBER 10/034,895	FILING DATE 12/28/2001 RULE	CLASS 428	GROUP ART UNIT 1773	ATTORNEY DOCKET NO. YAMAP0718USA
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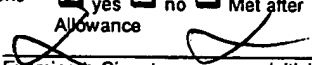
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** CONTINUING DATA ***** 
 This application is a DIV of 09/596,116 06/16/2000 PAT 6,436,526

** FOREIGN APPLICATIONS ***** 
 JAPAN 11-170486 06/17/1999
 JAPAN 11-352962 12/13/1999

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 16	TOTAL CLAIMS 54	INDEPENDENT CLAIMS 14
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature 	Initials		

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TITLE

Magneto-resistance effect element magneto-resistance effect memory cell, MRAM, and method for performing information write to or read from the magneto-resistance effect memory cell

<input type="checkbox"/> All Fees
<input type="checkbox"/> 1.16 Fees (Filing)